NSN 5962-01-110-6892

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-110-6892

Overall Height:

0.365 inches

Body Length:

0.810 inches

Body Width:

Between 0.270 inches and 0.305 inches

Body Height:

Between 0.105 inches and 0.145 inches

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and 3-state output and low power and w/enable and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

13 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

18.3 volts power source

Time Rating Per Chacteristic:

1200.00 nanoseconds propagation delay time, low to high level output and 1200.00 nanoseconds propagation delay time, high to low level

output

Memory Device Type:

Ram

Memory Capacity:

Unknown

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

NSN 5962-01-110-6892

Memory Microcircuit - Page 2 of 2

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